INTEGRATED CIRCUITS



Product data Supersedes data of 1996 Aug 28 2002 Sep 06



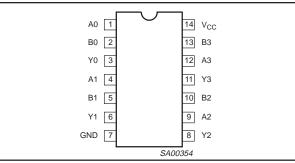


74LVT32

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25 °C; GND = 0 V	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay An, Bn to Yn	C _L = 50 pF; V _{CC} = 3.3 V	2.6 3.2	ns
C _{IN}	Input capacitance	$V_I = 0 V \text{ or } 3.0 V$	3	pF
I _{CCL}	Total supply current	Outputs Low; $V_{CC} = 3.6 V$	1	mA

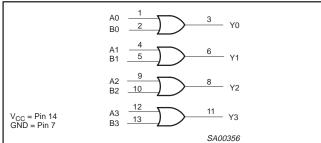
PIN CONFIGURATION



PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 2, 4, 5, 9, 10, 12, 13	An, Bn	Data inputs
3, 6, 8, 11	Yn	Data outputs
7	GND	Ground (0 V)
14	V _{CC}	Positive supply voltage

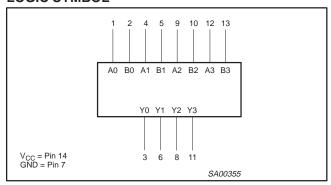
LOGIC DIAGRAM



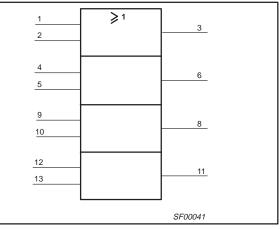
ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
14-Pin Plastic SO	–40 °C to +85 °C	74LVT32D	74LVT32D	SOT108-1
14-Pin Plastic SSOP	–40 °C to +85 °C	74LVT32DB	74LVT32DB	SOT337-1
14-Pin Plastic TSSOP	–40 °C to +85 °C	74LVT32PW	74LVT32PWDH	SOT402-1

LOGIC SYMBOL



LOGIC SYMBOL (IEEE/IEC)



FUNCTION TABLE

INPUTS		OUTPUT
Dna	Dnb	Qn
L	L	L
L	Н	Н
Н	L	Н
Н	Н	Н

NOTES:

H = High voltage level

L = Low voltage level

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ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V _I < 0	-50	mA
VI	DC input voltage ³		-0.5 to +7.0	V
I _{OK}	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V
		Output in High state	-32	
lout	DC output current	Output in Low state	64	mA
T _{stg}	Storage temperature range		–65 to 150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction 2.

The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER		LIMITS		
STMBOL			MAX	UNIT	
V _{CC}	DC supply voltage	2.7	3.6	V	
VI	Input voltage		5.5	V	
V _{IH}	High-level input voltage			V	
V _{IL}	Low-level Input voltage		0.8	V	
I _{OH}	High-level output current		-20	mA	
I _{OL}	Low-level output current		32	mA	
$\Delta t/\Delta v$	Input transition rise or fall rate; Outputs enabled		10	ns/V	
T _{amb}	Operating free-air temperature range	-40	+85	°C	

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DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions Voltages are referenced to GND (ground = 0 V)

			L	UNIT			
SYMBOL	PARAMETER	TEST CONDITIONS	Temp = -40°C to +85°C				
			MIN	TYP ¹	MAX		
V _{IK}	Input clamp voltage	$V_{CC} = 2.7 \text{ V}; \text{ I}_{IK} = -18 \text{ mA}$			-1.2	V	
		$V_{CC} = 2.7$ to 3.6 V; $I_{OH} = -100 \ \mu A$	V _{CC} -0.2				
V _{OH}	High-level output voltage	$V_{CC} = 2.7 \text{ V}; I_{OH} = -6 \text{ mA}$	2.4			V	
		V _{CC} = 3.0 V; I _{OH} = -20 mA	2.0				
	Low-level output voltage	V _{CC} = 2.7 V; I _{OL} = 100 μA			0.2		
V _{OL}		V _{CC} = 2.7 V; I _{OL} = 24 mA			0.5	V	
		V _{CC} = 3.0 V; I _{OL} = 32 mA			0.5		
		V _{CC} = 0 or 3.6 V; V _I = 5.5 V			10		
łı	Input leakage current	$V_{CC} = 3.6 \text{ V}; \text{ V}_{I} = V_{CC} \text{ or GND}$			±1	μA	
I _{OFF}	Output off current	$V_{CC} = 0 \text{ V}; \text{ V}_{1} \text{ or } \text{ V}_{O} = 0 \text{ to } 4.5 \text{ V}$			±100	μA	
I _{CCH}	Quiescent supply current	$V_{CC} = 3.6 \text{ V};$ Outputs High, $V_{I} = \text{GND or } V_{CC, I_{O}} = 0$			0.02	mA	
I _{CCL}	Quescent supply current	$V_{CC} = 3.6 \text{ V};$ Outputs Low, $V_I = \text{GND} \text{ or } V_{CC}, I_O = 0$	= 0 1		2		
ΔI_{CC}	Additional supply current per input pin ²	V_{CC} = 3 V to 3.6 V; One input at V_{CC} – 0.6 V, Other inputs at V_{CC} or GND			0.2	μΑ	
Cl	Input capacitance	$V_1 = 3 V \text{ or } 0$		3		pF	

NOTES:

1. All typical values are at V_{CC} = 3.3 V and T_{amb} = 25 °C. 2. This is the increase in supply current for each input at the specificed voltage level other than V_{CC} or GND.

AC CHARACTERISTICS

GND = 0 V; $t_R = t_F = 2.5 \text{ ns}$; $C_L = 50 \text{ pF}$, $R_L = 500 \Omega$; $T_{amb} = -40 \text{ }^{\circ}\text{C}$ to +85 $^{\circ}\text{C}$.

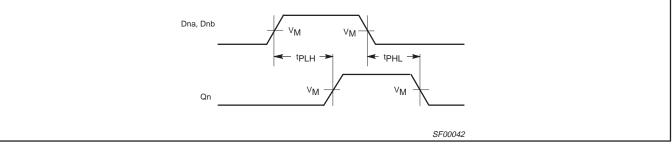
SYMBOL	PARAMETER	WAVEFORM	V _{CC}	= 3.3 V \pm 0	.3 V	V _{CC} = 2.7 V	UNIT
			MIN	TYP ¹	MAX	MAX	
t _{PLH} t _{PHL}	Propagation delay An, Bn to Yn	1	1.0 1.0	2.6 3.2	3.8 4.6	4.5 4.9	ns

NOTE:

1. All typical values are at V_{CC} = 3.3 V and T_{amb} = 25 °C.

AC WAVEFORMS

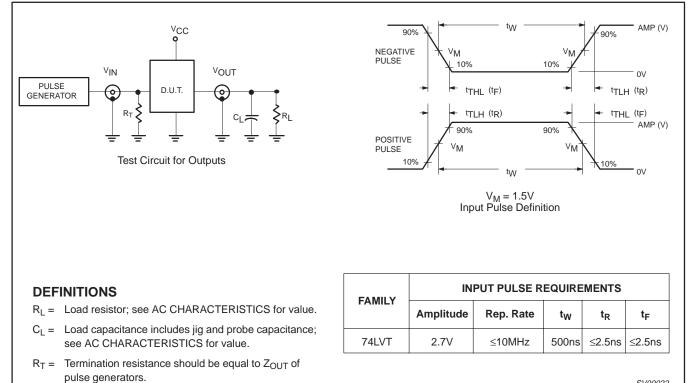
 V_{M} = 1.5 V, V_{IN} = GND to 2.7 V



Waveform 1. Propagation delay for inverting outputs

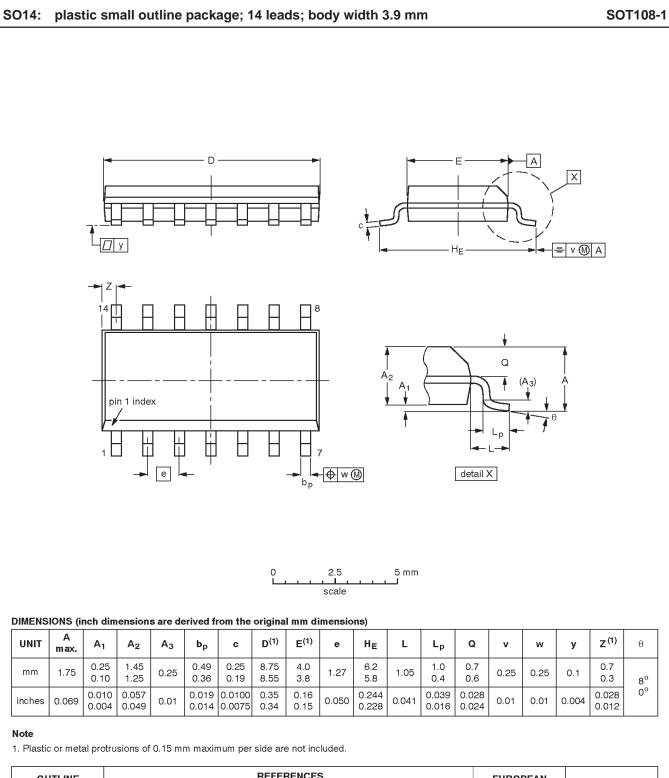
74LVT32

TEST CIRCUIT AND WAVEFORMS



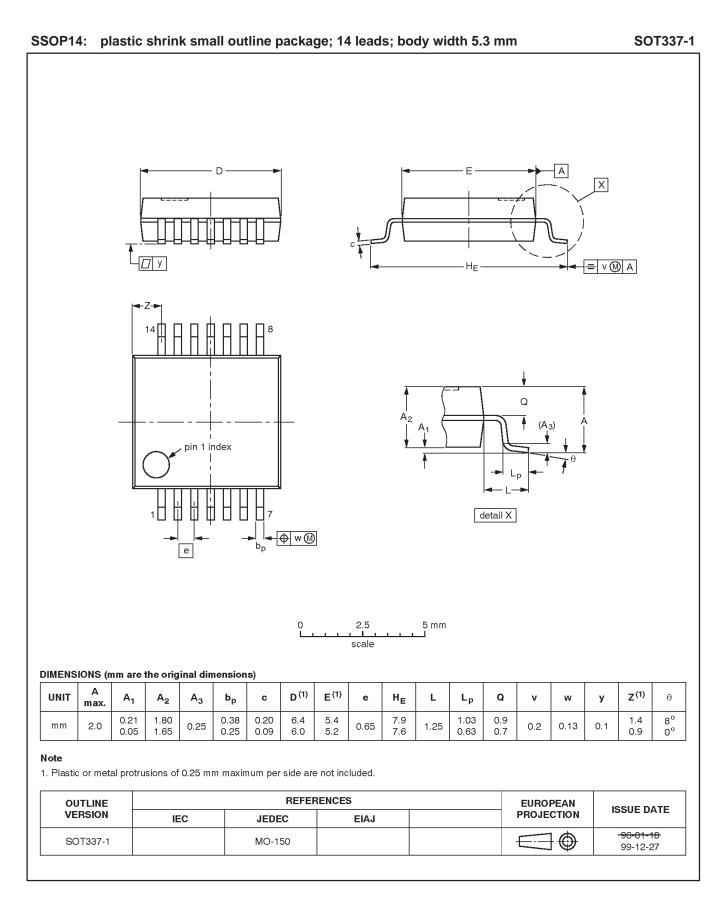
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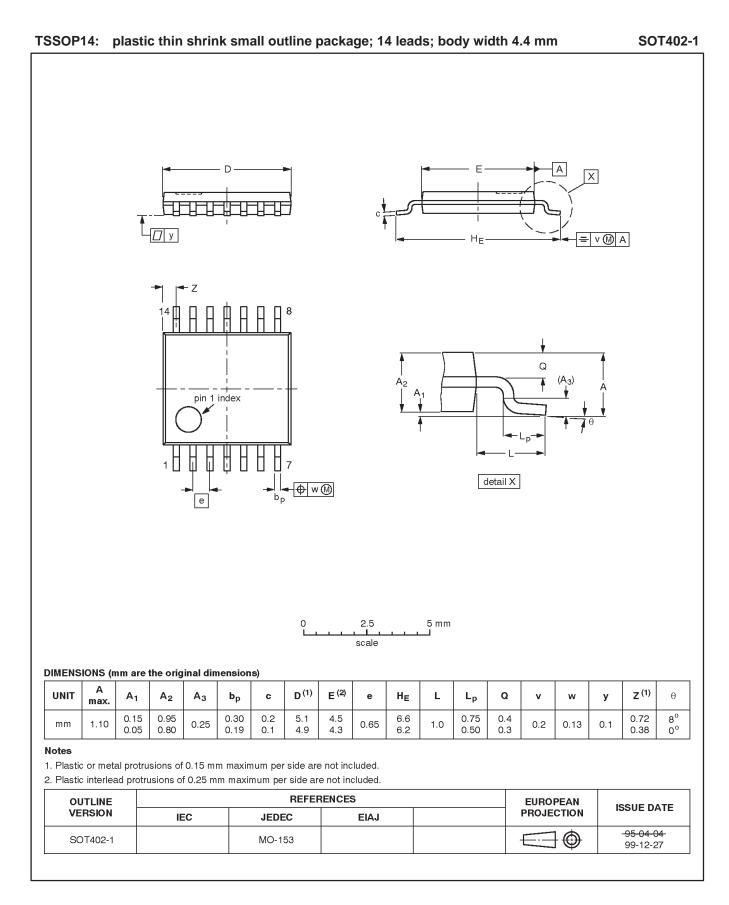


OUTLINE		REFER	ENCES	EUROPEAN		
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT108-1	076E06	MS-012			-97-05-22 99-12-27	

74LVT32



74LVT32



Product data

REVISION HISTORY

Rev	Date	Description
_2	2002 Sep 06	Product data (9397 750 10298); supersedes Product specification 74LVT32 of 1996 Aug 28.
		Modifications: There are no changes to any data. Document re-issued to improve quality of package outline drawings display only.
-	1996 Aug 28	Product specification; initial version. Engineering Change Notice: 853-1873 17244 (date: 1996 Aug 28).

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Data sheet status

Data sheet status ^[1]	Product status ^[2]	Definitions
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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[1] Please consult the most recently issued data sheet before initiating or completing a design.

[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

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Date of release: 09-02

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Document order number:

9397 750 10298

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